Normal-Conducting Photoinjector for High Power CW FEL

Sergey Kurennoy, LANL, Los Alamos, NM, USA

An RF photoinjector capable of producing high continuous average current with low emittance and energy spread is a key enabling technology for high power CW FEL. We designed a 2.5-cell, π -mode, 700-MHz normal-conducting RF photoinjector cavity with magnetic emittance compensation. With the electric field gradients of 7, 7, and 5 MV/m in the three subsequent cells, the photoinjector will produce a 2.5-MeV electron beam with 3-nC charge per bunch and the transverse rms emittance below 7 mm-mrad.

Electromagnetic modeling was used to optimize the RF cavity, ridge-loaded tapered waveguides, and RF couplers, which led to a new, improved coupler iris design. The results, combined with a thermal and stress analysis, show that the challenging problem of cavity cooling can be successfully solved. The manufacturing of a demo 100-mA (at 35 MHz bunch repetition rate) photoinjector is underway. The design is scalable to higher power levels by increasing the electron bunch repetition rate, and provides a path to a MW-class amplifier FEL.





Normal-Conducting RF Photoinjector

- Requirements:
 - CW, 700-MHz RF; emittance < 10 mm·mrad at the wiggler
 - 3 nC per bunch, 100 mA at 35-MHz bunch rep rate (\rightarrow 1 A)
- Design:
 - split cavities: 2.5-cell PI (old 777 design: 7,7,7 MV/m, 2.70 MeV)

 $\rightarrow \underline{\text{new 775 design: 7,7,5 MV/m, 2.54 MeV}}$

+ booster (4 cells, 4.5 MV/m, 5.5 MeV)

- PI: 2.5 cells, emittance-compensated, on-axis electric coupling
- − 100 mA: P_w (<u>668 kW</u>) + P_b (254 kW) → 1 A: <u>668 kW</u> + 2540 kW
- EM modeling: cavity, RF couplers, and ridge-loaded tapered waveguides
- Beam dynamics TS2 versus Parmela
- Thermal & stress analysis, manufacturing \rightarrow AES, *Medford, NY*



2.5-cell RF Photoinjector Cavity



MAFIA model of 2.5-cell cavity with magnets and vacuum plenum



2.5-cell RF Photoinjector Cavity



2.5-cell PI with vacuum plenum - SF & MAFIA results



Normal-Conducting RF Photoinjector



2.5-cell PI with emittance-compensating magnets (left) and vacuum plenum (right)



NC RF Photoinjector: Microwave Studio Modeling



Electric field of π -mode in 2.5-cell cavity: E₀=7 MV/m in cells 1&2, 5 MV/m in cell 3.



NC RF Photoinjector: Microwave Studio Modeling



Surface current distribution for the π -mode in 2.5-cell photoinjector cavity (775)



RF Power for NC Photoinjector

- <u>922 kW of RF input power</u> for 100 mA beam current:
 - CW, 700-MHz RF power is fed through two waveguides
- Ridge-loaded tapered waveguides (RLWG)
 - Design is based on LEDA RFQ and SNS power couplers
 - Ridge profile is found by SF calculations for cross sections (LY), and checked using MicroWave Studio (MWS) 3-D calculations
- "Dog-bone" shaped RF coupling irises







<u>RF coupler model</u>. Tapered ridge-loaded waveguides are coupled to the 3rd cell of photoinjector cavity (modeled here by a pillbox) via irises cut through thick walls.



EM Modeling of RF Coupler

Details of coupler irises



<u>RF coupler model</u>. Details of coupler irises and ridge-loaded tapered waveguides. The wall thickness near the iris is 1.2", the iris gap width is 1.8 mm.



EM Modeling of RF Coupler

Procedure

The required WG-cavity coupling is $\beta_c = \frac{P_w + P_b}{P_w} = 1.38.$

For the pillbox model, the required coupling is $\beta_{pb} = \beta_c \frac{W_c}{W_{pb}} \left(\frac{H_{pb}}{H_c}\right)^2 \frac{Q_{pb}}{Q_c}$. Then the required Q_e for the model is $Q_e = \frac{Q_c}{\beta_c} \frac{W_{pb}}{W_c} \left(\frac{H_c}{H_{pb}}\right)^2 = 1933$.

We calculate Q_e in the model directly using time-domain simulations with MicroWave Studio (MWS), and adjust the coupling. After that, again in MWS, an RF signal with a constant amplitude is fed into waveguides to find the match point (P_{out} = 0), and calculate the field and surface power distributions at the match.

S.S. Kurennoy, L.M. Young. "RF Coupler for High-Power CW FEL Photoinjector", PAC2003, p. 3515.



EM Modeling of RF Coupler: Time Domain (TD)





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EM Modeling of RF Coupler

From energy balance $P_{in} - P_{out} = P_w + P_b \equiv \beta P_w$ one can find power ratio

$$\frac{P_{out}}{P_{in}} = 1 - \frac{\beta}{\beta_c} f\left(\alpha, \frac{\beta}{\beta_c}\right), \quad \text{where} \quad f\left(\frac{1}{y}, x\right) = \left(\frac{1 + y\sqrt{1 + \left(y^2 - 1\right)x}}{1 + y^2 x}\right)^2.$$

Coefficient $0 < \alpha < 1$ is the amplitude ratio of the input and reflected waves, $1 - \alpha < < 1$. For $\beta = 1$, $\beta_c = 1.38$, ratio $P_{out}/P_{in} \approx 0.025$, practically independent of value of α .





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EM Modeling of RF Coupler: TD Results

Clamp to range: (Min: 0/ Max: 20)



Surface magnetic fields at the match point from MWS time-domain simulations



EM Modeling of RF Coupler: TD Results

Clamp to range: (Min: 0/ Max: 20)

Maximal power density is 120 W/cm² at 461 kW RF input power per waveguide



Surface currents near the irises at the match from MWS time-domain simulations



A/m 20 19

EM Modeling of RF Coupler: TD Results



Surface currents near the irises at thermal-test point (no beam, 2.5% reflection)



EM Modeling of RF Coupler: Eigensolver X-check



Surface currents from MWS eigensolver calculations (mesh 3.006M for 1/8)



EM Modeling of RF Coupler: Results for 775

MWS eigensolver

MWS time domain

Mesh. Max dP/ds. W/cm² K points 111 107 111* 104* 312 120 312* 119* 760 114 760* 114*

Mesh, K points	Max <i>dP/d</i> s, W/cm²
86	95
201	109
734	120
1539	122
3006	118

Compare to 43 W/cm² at smooth wall in the 3^{rd} cell far from irises: power ratio is < 2.8 \rightarrow field enhancement due to irises is < 1.65

> For 777 design max *dP/ds* was 220 W/cm²

* W/o beam, 342 kW per WG (incl. 2.5% reflection)

For reference: in the LEDA RFQ couplers max *dP/ds* ≈ 150 W/cm², while the power ratio (max / smooth wall) was about 10

Maximal values of surface power density from MWS calculations



NC Photoinjector, RF Couplers : Summary

- 100-mA operation of normal conducting photoinjector requires almost 1 MW of CW 700-MHz RF power that will be fed through two ridge-loaded tapered waveguides.
- RF coupler design is based on LEDA RFQ and SNS couplers. The coupler-cavity system is modeled using a novel approach with direct MWS time-domain simulations. Results for the maximal power density are checked using eigensolvers.
- The coupler design is optimized using 3-D EM modeling to reduce the maximal surface power density on the coupler irises:
 - Increased hole radius and wall thickness; blended iris edges;
 - Field enhancement is only 65% compared to smooth cavity walls.
- In the 775 PI cavity, the max power density near the irises is only 15% higher than max in the smooth cavity. This design reduces stresses and facilitates cavity cooling. Thermal management is still challenging but feasible.
- The PI cavity is being manufactured by AES. Its thermal tests with full RF load are scheduled at LANL (LEDA) in 2005.



RF Cavity Model with 4 RLWG: Matched at 0.46 A



Surface currents at the match point from MWS time-domain simulations





Parmela simulations of 2.5-cell PI + booster + linac (L. Young)



mm-mrad



Comparison of MAFIA TS2 and Parmela results for 3-nC bunch charge







MAFIA TS2 simulations of 2.5-cell PI (wake fields included)





MAFIA TS2, 4.5M Parmela sc3d, 100K

10

Parmela sc3d, 800K, 64³

20

2

1

00

MAFIA TS2 simulations of 2.5-cell PI: 10-nC bunch charge

z. cm

40

30

60

50



Beam dynamics in photoinjector: Summary

- 100-mA operation of the normal-conducting 700-MHz CW photoinjector requires 3-nC bunches at 35-MHz bunch repetition rate. Higher currents are achievable with higher bunch repetition rates.
- Beam dynamics in the PI RF cavity is modeled using Parmela and MAFIA TS2 particle-in-cell (PIC) simulations. Results for 3 nC are in agreement.
- Wake fields effects are weak, even for 10 nC. TS2 simulations with multiple bunches at 350-MHz repetition rate show identical parameters of bunches at the cavity exit.
- The PI cavity is being manufactured by AES. Its thermal tests with full RF load are scheduled at LANL (LEDA) in 2005.

